

2PC4081 NPN general-purpose transistor Rev. 06 — 17 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN transistor in a SOT323 (SC-70) plastic package. The PNP complement is 2PA1576.

1.2 Features

- Low current (max. 150 mA)
- Low voltage (max. 50 V)

1.3 Applications

- General-purpose switching
- Small signal amplification

2. Pinning information

Table 1. **Pinning**

Pin	Description	Simplified outline Symbol
1	base	<u>_</u> .
2	emitter	3
3	collector	1 1 2 2
		sym021

Ordering information 3.

Ordering information Table 2.

Type number	Package	Package				
	Name	Description	Version			
2PC4081Q	SC-70	plastic surface mounted package; 3 leads	SOT323			
2PC4081R						
2PC4081S						



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Marking

Table 3. **Marking codes**

Type number	Marking code ^[1]
2PC4081Q	Z*Q
2PC4081R	Z*R
2PC4081S	Z*S

^{[1] * = -:} made in Hong Kong

5. Limiting values

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	60	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	7	V
I _C	collector current (DC)		-	150	mA
I _{CM}	peak collector current		-	200	mA
I_{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

Thermal characteristics 6.

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Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> -	-	625	K/W

^[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

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^{* =} t: made in Malaysia

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Characteristics

Table 6. **Characteristics**

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$I_E = 0 A; V_{CB} = 30 V$	-	-	100	nA
		$I_E = 0 \text{ A}; V_{CB} = 30 \text{ V};$ $T_j = 150 \text{ °C}$	-	-	5	μА
I _{EBO}	emitter-base cut-off current	$I_C = 0 A; V_{EB} = 4 V$	-	-	100	nA
h _{FE}	DC current gain	$I_C = 1 \text{ mA}; V_{CE} = 6 \text{ V}$				
	2PC4081Q		120	-	270	
	2PC4081R		180	-	390	
	2PC4081S		270	-	560	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$	[1] -	-	400	mV
C _c	collector capacitance	$I_E = i_e = 0 \text{ A};$ $V_{CB} = 12 \text{ V}; f = 1 \text{ MHz}$	-	2	3.5	pF
f _T	transition frequency	$I_C = 2 \text{ mA}; V_{CE} = 12 \text{ V};$ f = 100 MHz	100	-	-	MHz

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

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Package outline

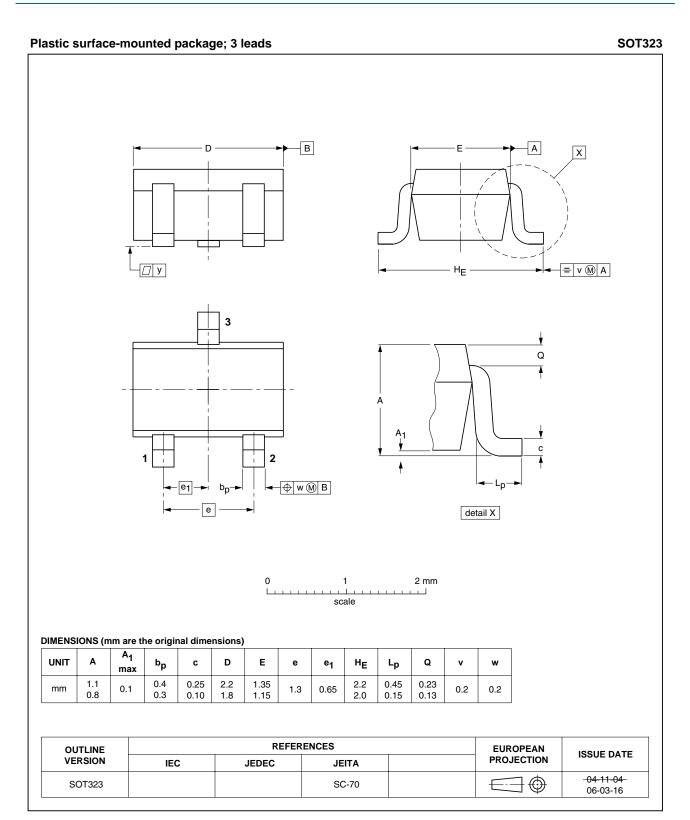


Fig 1. Package outline SOT323 (SC-70)

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9. Revision history

Table 7. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
2PC4081_6	20091117	Product data sheet	-	2PC4081_5
Modifications:	including new le content.	was changed to reflect the egal definitions and disclair age outline SOT323 (SC-70	ners. No changes we	
2PC4081_5	20041125	Product data sheet	-	2PC4081_4
2PC4081_4	19990408	Product specification	-	2PC4081_3
2PC4081_3	19970704	Product specification	-	2PC4081_2
2PC4081_2	19931213	n.a.	-	n.a.

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10. Legal information

Data sheet status 10.1

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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